

/ Descriptions

Ultrafast Recovery Diode in a TO-263 Plastic Package.

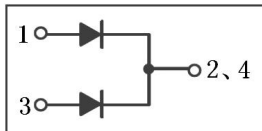
/ Features

Silicon epitaxial process to produce ultrafast recovery diode with low reverse leakage current and high reliability.

/ Applications

For high frequency, high voltage, high current rectifier diode, freewheeling diode, PFC circuit.

/ Equivalent Circuit



/ Pinning



PIN1 Anode

PIN 2 4 Cathode

PIN 3 Anode

/ h_{FE} Classifications & Marking

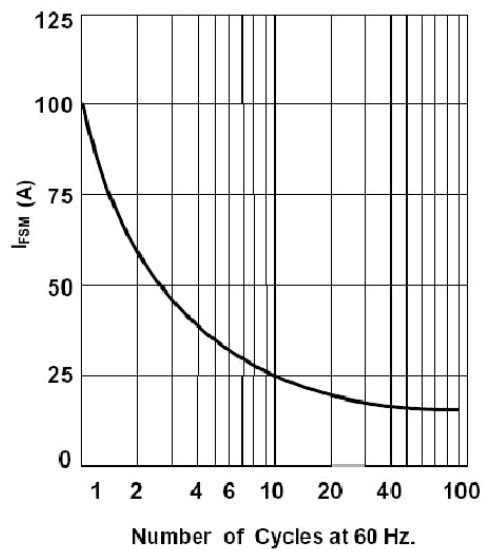
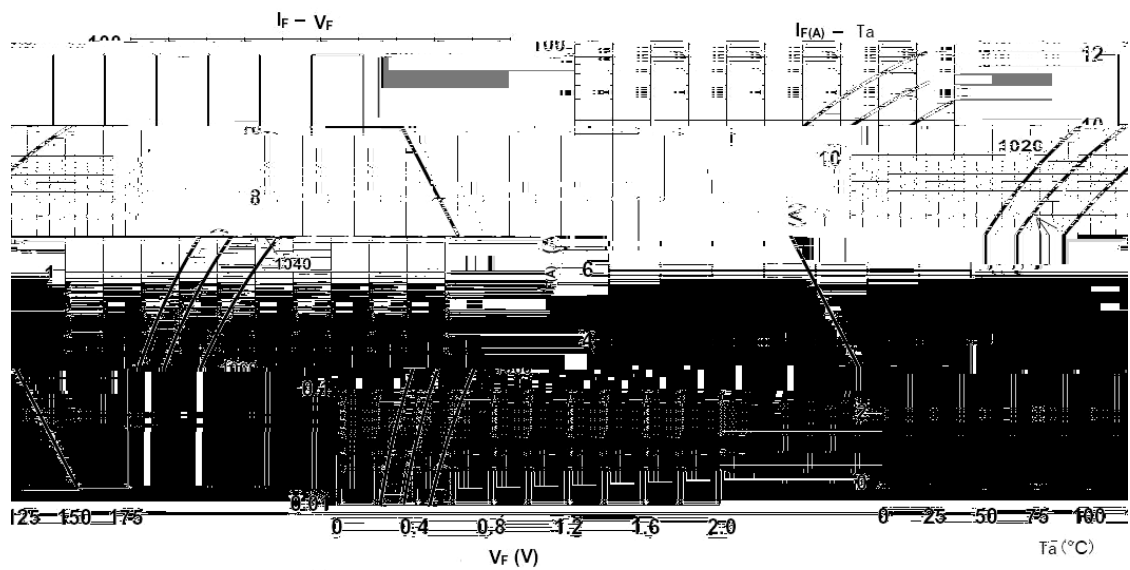
- 。 See Marking Instructions.

BRMUR1040CTBD

Rev.B .Mar.-2019

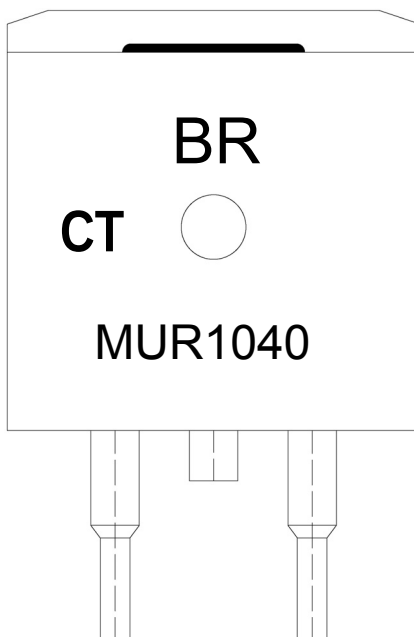
Parameter	Symbol	Rating	Unit
Peak Repetitive Reverse Voltage	V_{RRM}	400	V
RMS Voltage	V_{RMS}	280	V
DC Blocking Voltage	V_{DC}	400	V
Peak Repetitive Forward Current	I_F	10	A
Non Repetitive Peak Surge Current	I_{FSM}	100	A
Maximum Thermal Resistance Junction to Case	$R_{\theta Jc}$	2.8	/W
Storage Temperature Range	T_{stg}	-55~150	

/ Electrical Characteristic Curve





/ Marking Instructions



Note:

BR:

Company Code

MUR1040:

Product Type

CT:

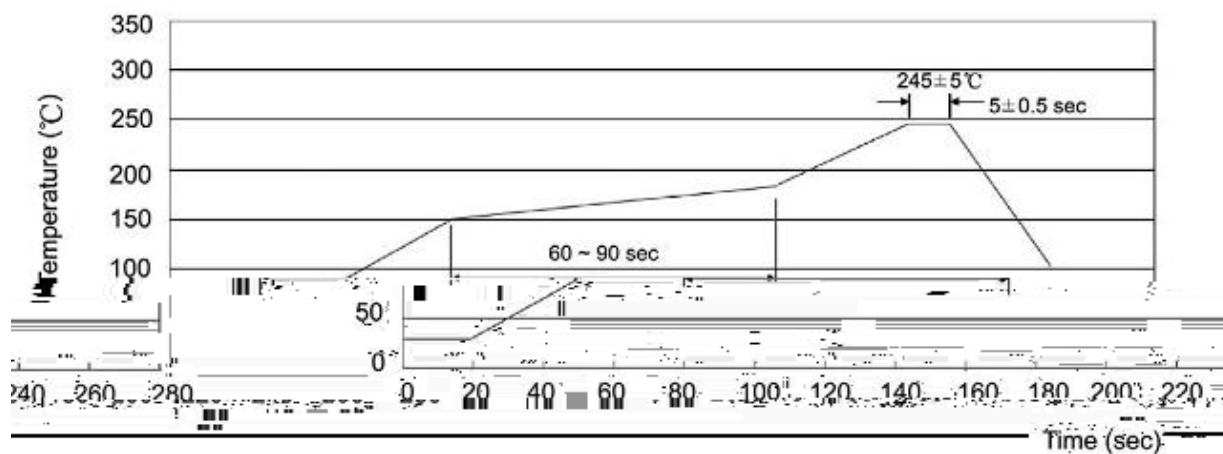
Internal Structure

****:

Lot No. Code, code change with Lot No.



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Note:

- | | | | | | |
|---|-----|-----|----|----------|---|
| 1 | 150 | 180 | 60 | 90sec; | 1.Preheating:150~180 , Time:60~90sec. |
| 2 | 255 | 5 | 5 | 0.5sec; | 2.Peak Temp.:255 5 , Duration:5 0.5sec. |
| 3 | | | 2 | 10 /sec. | 3. Cooling Speed: 2~10 /sec. |

/ Resistance to Soldering Heat Test Conditions

260	5	10	1 sec.	Temp.:260±5	Time:10±1 sec
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/ Packaging SPEC.

/ REEL

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	只 卷盘	卷盘 盒	只 盒	盒 箱	只 箱		盒	箱
						"		

/ TUBE

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	只 套管	套管 盒	只 盒	盒 箱	只 箱	套管	盒	箱

/ Notices